

### Low Voltage 16-Bit D-TYPE LATCH with 5V Tolerant Inputs and Outputs

The TC74LCX16373AFT is a high performance CMOS 16-bit D-TYPE LATCH. Designed for use in 3.3 Volt systems, it achieves high speed operation while maintaining the CMOS low power dissipation.

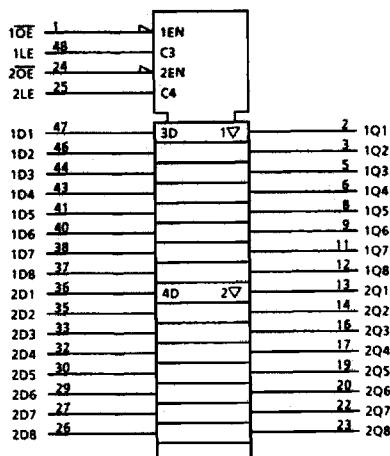
The device is designed for low voltage (3.3V)  $V_{CC}$  applications, but it could be used to interface to 5V supply environment for both inputs and outputs.

This 16-bit D-type latch is controlled by a latch enable input (LE) and an output enable input ( $\overline{OE}$ ) which are common to each byte. It can be used as two 8-bit latches or one 16-bit latch. When the  $\overline{OE}$  input is high, the outputs are in a high impedance state.

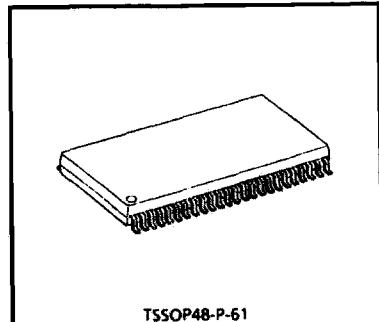
All inputs are equipped with protection circuits against static discharge.

### Features

- Low Voltage Operation:  $V_{CC} = 2.0 \sim 3.6V$
- High Speed:  $t_{pd} = 7.0ns$  (Max.) at  $V_{CC} = 3.0 \sim 3.6V$
- Output Current:  $I_{OPL}/I_{OL} = 24mA$  (Min.)  $V_{CC} = 3.0V$
- Latch up Performance:  $\pm 500mA$
- Package: TSSOP (Thin Shrink Small Outline Package)
- Power down protection is provided on all inputs and outputs.



IEC Logic Symbol



Weight : 0.25 g (Typ.)

|                 |    |    |          |
|-----------------|----|----|----------|
| $\overline{OE}$ | 1  | 48 | 1LE      |
| 1Q1             | 2  | 47 | 1D1      |
| 1Q2             | 3  | 46 | 1D2      |
| GND             | 4  | 45 | GND      |
| 1Q3             | 5  | 44 | 1D3      |
| 1Q4             | 6  | 43 | 1D4      |
| $V_{CC}$        | 7  | 42 | $V_{CC}$ |
| 1Q5             | 8  | 41 | 1D5      |
| 1Q6             | 9  | 40 | 1D6      |
| GND             | 10 | 39 | GND      |
| 1Q7             | 11 | 38 | 1D7      |
| 1Q8             | 12 | 37 | 1D8      |
| 2Q1             | 13 | 36 | 2D1      |
| 2Q2             | 14 | 35 | 2D2      |
| GND             | 15 | 34 | GND      |
| 2Q3             | 16 | 33 | 2D3      |
| 2Q4             | 17 | 32 | 2D4      |
| $V_{CC}$        | 18 | 31 | $V_{CC}$ |
| 2Q5             | 19 | 30 | 2D5      |
| 2Q6             | 20 | 29 | 2D6      |
| GND             | 21 | 28 | GND      |
| 2Q7             | 22 | 27 | 2D7      |
| 2Q8             | 23 | 26 | 2D8      |
| $2OE$           | 24 | 25 | 2LE      |

(TOP VIEW)

Pin Assignment

Truth Table

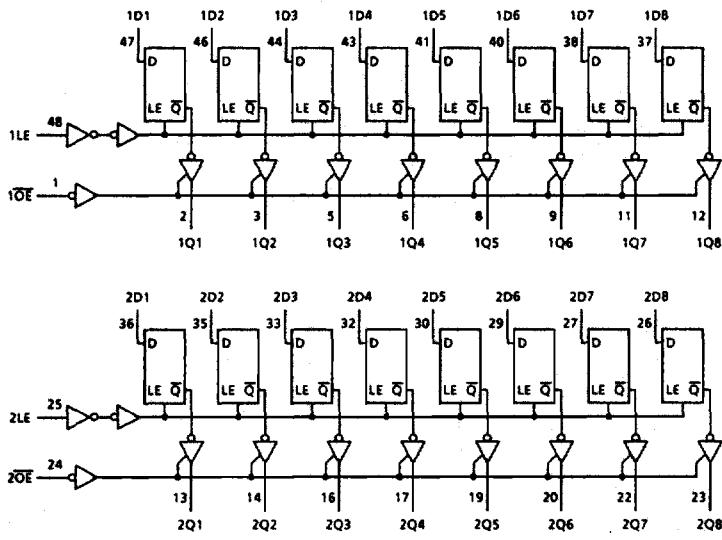
| Input       |     | Output    |           |
|-------------|-----|-----------|-----------|
| $\bar{1OE}$ | 1LE | 1D1 - 1D8 | 1Q1 - 1Q8 |
| H           | X   | X         | Z         |
| L           | L   | X         | Qn        |
| L           | H   | L         | L         |
| L           | H   | H         | H         |

| Input       |     | Output    |           |
|-------------|-----|-----------|-----------|
| $\bar{2OE}$ | 2LE | 2D1 - 2D8 | 2Q1 - 2Q8 |
| H           | X   | X         | Z         |
| L           | L   | X         | Qn        |
| L           | H   | L         | L         |
| L           | H   | H         | H         |

X : Don't Care

Z : High Impedance

Qn : No Change

**System Diagram**

**Absolute Maximum Ratings**

| Parameter   | Symbol              | Rating                            | Unit |
|---|---------------------|-----------------------------------|------|
| Power Supply Voltage                              | V <sub>CC</sub>     | -0.5 ~ 7.0                        | V    |
| DC Input Voltage                                  | V <sub>IN</sub>     | -0.5 ~ 7.0                        | V    |
| DC Bus I/O Voltage                                | V <sub>I/O</sub>    | -0.5 ~ 7.0 (*1)                   | V    |
|   |                     | -0.5 ~ V <sub>CC</sub> + 0.5 (*2) |      |
| Input Diode Current                               | I <sub>IK</sub>     | -50                               | mA   |
| Output Diode Current                              | I <sub>OK</sub>     | ±50 (*3)                          | mA   |
| DC Output Current                                 | I <sub>OUT</sub>    | ±50                               | mA   |
| Power Dissipation                                 | P <sub>D</sub>      | 400                               | mW   |
| DC V <sub>CC</sub> /Ground Current Per Supply Pin | I <sub>CC/GND</sub> | ±100                              | mA   |
| Storage Temperature                               | T <sub>STG</sub>    | -65 ~ 150                         | °C   |

(\*1) Off-State

(\*2) High or Low State. I<sub>OUT</sub> absolute maximum rating must be observed(\*3) V<sub>OUT</sub> < GND, V<sub>OUT</sub> > V<sub>CC</sub>**Recommended Operating Range**

| Parameter                | Symbol                           | Rating                   | Unit |
|--------------------------|----------------------------------|--------------------------|------|
| Supply Voltage           | V <sub>CC</sub>                  | 2.0 ~ 3.6                | V    |
|                          |                                  | 1.5 ~ 3.6 (*4)           |      |
| Input Voltage            | V <sub>IN</sub>                  | 0 ~ 5.5                  | V    |
| Bus I/O Voltage          | V <sub>I/O</sub>                 | 0 ~ 5.5 (*5)             | V    |
|                          |                                  | 0 ~ V <sub>CC</sub> (*6) |      |
| Output Current           | I <sub>OH</sub> /I <sub>OL</sub> | ±24 (*7)                 | mA   |
|                          |                                  | ±12 (*8)                 |      |
| Operating Temperature    | T <sub>OPR</sub>                 | -40 ~ 85                 | °C   |
| Input Rise and Fall Time | dI/dV                            | 0 ~ 10 (*9)              | ns/V |

(\*4) Data Retention Only

(\*5) Off-State

(\*6) High or Low State

(\*7) V<sub>CC</sub> = 3.0 ~ 3.6V(\*8) V<sub>CC</sub> = 2.7 ~ 3.0V(\*9) V<sub>IN</sub> = 0.8 ~ 2.0V, V<sub>CC</sub> = 3.0V

**Electrical Characteristics****DC Characteristics (Ta = -40 ~ 85°C)**

| Parameter                             |           | Symbol           | Test Condition  |   | V <sub>CC</sub> (V)            | Min.                                       | Max.                      | Unit |   |
|---------------------------------------|-----------|------------------|---|---|--------------------------------|--|---------------------------|------|---|
| Input Voltage                         | "H" Level |                  | V <sub>IH</sub>   |   |                                | 2.7 ~ 3.6                                  | 2.0                       | -    | V |
|                                       | "L" Level |                  | V <sub>IL</sub>   |   |                                | 2.7 ~ 3.6                                  | -                         | 0.8  | V |
| Output Voltage                        | "H" Level | V <sub>OH</sub>  | V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>                                | I <sub>OH</sub> = -100µA<br>I <sub>OH</sub> = -12mA<br>I <sub>OH</sub> = -18mA<br>I <sub>OH</sub> = -24mA | 2.7 ~ 3.6                      | V <sub>CC</sub> - 0.2<br>2.7<br>3.0<br>3.0 | -                         | -    | V |
|                                       | "L" Level | V <sub>OL</sub>  |   | I <sub>OL</sub> = 100µA<br>I <sub>OL</sub> = 16mA<br>I <sub>OL</sub> = 12mA<br>I <sub>OL</sub> = 24mA     | 2.7 ~ 3.6<br>3.0<br>2.7<br>3.0 | -<br>-<br>-<br>-                           | 0.2<br>0.4<br>0.4<br>0.55 | V    |   |
| Input Leakage Current                 |           | I <sub>IN</sub>  | V <sub>IN</sub> = 0 ~ 5.5V  |   | 2.7 ~ 3.6                      | -  | ±5.0                      | µA   |   |
| 3-State Output Off-State Current      |           | I <sub>OZ</sub>  | V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub><br>V <sub>OUT</sub> = 0 ~ 5.5V |   | 2.7 ~ 3.6                      | -  | ±5.0                      | µA   |   |
| Power Off Leakage Current             |           | I <sub>OFF</sub> | V <sub>IN</sub> / V <sub>OUT</sub> = 5.5V   |   | 0                              | -  | 10.0                      | µA   |   |
| Quiescent Supply Current              |           | I <sub>CC</sub>  |   | V <sub>IN</sub> = V <sub>CC</sub> or GND  | 2.7 ~ 3.6                      | -  | 20.0                      | µA   |   |
|                                       |           |                  |   | V <sub>IN</sub> / V <sub>OUT</sub> = 3.6 ~ 5.5V   | 2.7 ~ 3.6                      | -  | ±20.0                     |      |   |
| Increase in I <sub>CC</sub> per Input |           | ΔI <sub>CC</sub> | V <sub>IH</sub> = V <sub>CC</sub> - 0.6V  |   | 2.7 ~ 3.6                      | -  | 500                       | µA   |   |

## AC Electrical Characteristics (Ta = -40 ~85°C)

| Parameter                       | Symbol                                 | Test Condition | V <sub>CC</sub> (V) | Min.       | Max.       | Unit |
|---------------------------------|--|----------------|---------------------|------------|------------|------|
|                                 |  |                |                     |            |            |      |
| Propagation Delay Time (D - Q)  | t <sub>pLH</sub><br>t <sub>pHL</sub>   | (Fig. 1, 2)    | 2.7<br>3.3±0.3      | —<br>1.5   | 8.0<br>7.0 | ns   |
| Propagation Delay Time (LE - Q) | t <sub>pLH</sub><br>t <sub>pHL</sub>   | (Fig. 1, 2)    | 2.7<br>3.3±0.3      | —<br>1.5   | 8.0<br>7.0 | ns   |
| 3-State Output Enable Time      | t <sub>pZL</sub><br>t <sub>pZH</sub>   | (Fig. 1, 3)    | 2.7<br>3.3±0.3      | —<br>1.5   | 8.2<br>7.2 | ns   |
| 3-State Output Disable Time     | t <sub>pZL</sub><br>t <sub>pHZ</sub>   | (Fig. 1, 3)    | 2.7<br>3.3±0.3      | —<br>1.5   | 8.2<br>7.2 | ns   |
| Minimum Pulse Width (LE)        | t <sub>w(H)</sub><br>t <sub>w(H)</sub> | (Fig. 1, 2)    | 2.7<br>3.3±0.3      | 3.0<br>3.0 | —<br>—     | ns   |
| Minimum Setup Time              | t <sub>s</sub>                         | (Fig. 1, 2)    | 2.7<br>3.3±0.3      | 2.5<br>2.5 | —<br>—     | ns   |
| Minimum Hold Time               | t <sub>h</sub>                         | (Fig. 1, 2)    | 2.7<br>3.3±0.3      | 1.5<br>1.5 | —<br>—     | ns   |
| Output to Output Skew           | t <sub>osLH</sub><br>t <sub>osHL</sub> | (*10)          | 2.7<br>3.3±0.3      | —<br>—     | —<br>1.0   | ns   |

(\*10) Parameter guaranteed by design. (t<sub>osLH</sub> = | t<sub>pLHm</sub> - t<sub>pLHn</sub> |, t<sub>osHL</sub> = | t<sub>pHLM</sub> - t<sub>pHLn</sub> |)Dynamic Switching Characteristics (Ta = 25°C, Input t<sub>i</sub> = t<sub>l</sub> = 2.5ns, C<sub>L</sub> = 50pF, R<sub>L</sub> = 500Ω)

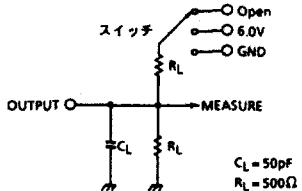
| Parameter                                    | Symbol            | Test Condition                               | V <sub>CC</sub> (V) | Typical | Unit |
|--|-------------------|--|---------------------|---------|------|
|  |                   |  |                     |         |      |
| Quiet Output Maximum Dynamic V <sub>OL</sub> | V <sub>OLP</sub>  | V <sub>IH</sub> = 3.3V, V <sub>IL</sub> = 0V | 3.3                 | 0.8     | V    |
| Quiet Output Minimum Dynamic V <sub>OL</sub> | V <sub>OLVL</sub> | V <sub>IH</sub> = 3.3V, V <sub>IL</sub> = 0V | 3.3                 | 0.8     | V    |

## Capacitive Characteristics (Ta = 25°C)

| Parameter                     | Symbol           | Test Condition                | V <sub>CC</sub> (V) | Typical | Unit |
|-------------------------------|------------------|-------------------------------|---------------------|---------|------|
|                               |                  |                               |                     |         |      |
| Input Capacitance             | C <sub>IN</sub>  | —                             | 3.3                 | 7       | pF   |
| Bus Input Capacitance         | C <sub>OUT</sub> | —                             | 3.3                 | 8       | pF   |
| Power Dissipation Capacitance | C <sub>PD</sub>  | f <sub>IN</sub> = 10MHz (*11) | 3.3                 | 25      | pF   |

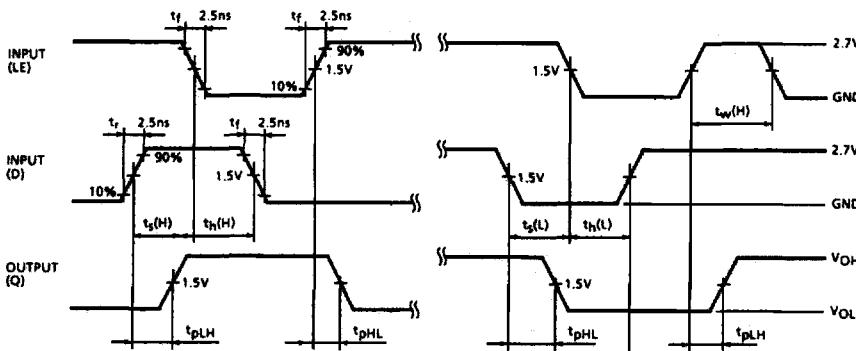
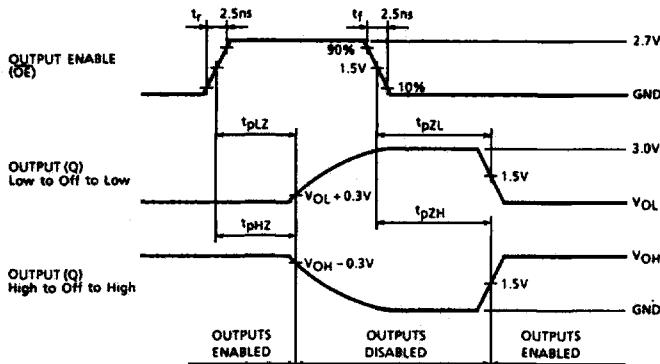
(\*11) C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.  
Average operating current can be obtained by the equation: I<sub>CC</sub> (opr.) = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>IN</sub> + I<sub>CC</sub>/16 (per latch)

Fig.1 Test circuit



| Parameter          | Switch |
|--------------------|--------|
| $t_{PLH}, t_{PHL}$ | Open   |
| $t_{PLZ}, t_{PZL}$ | 6.0V   |
| $t_{PZH}, t_{PZL}$ | GND    |
| $t_W, t_S, t_h$    | Open   |

AC wave form

Fig.2  $t_{PLH}, t_{PHL}, t_w, t_s, t_h$ Fig.3  $t_{PLZ}, t_{PZH}, t_{PZL}, t_{PZL}$ 

- This technical data may be controlled under U.S. Export Administration Regulations and may be subject to the approval of the U.S. Department of Commerce prior to export. Any export or re-export, directly or indirectly, in contravention of the U.S. Export Administration Regulations is strictly prohibited.
- LIFE SUPPORT POLICY**  
Toshiba products described in this document are not authorized for use as critical components in life support systems without the written consent of the appropriate officer of Toshiba America, Inc. Life support systems are either systems intended for surgical implant in the body or systems which sustain life. A critical component in any component of a life support system whose failure to perform may cause a malfunction of the life support system, or may affect its safety or effectiveness.
- The information in this document has been carefully checked and is believed to be reliable; however no responsibility can be assumed for inaccuracies that may not have been caught. All information in this data book is subject to change without prior notice. Furthermore, Toshiba cannot assume responsibility for the use of any license under the patent rights of Toshiba or any third parties.